

# Ultra Low Noise, Medium Current D-PHEMT Transistor

## SAV-331+

50Ω 10 to 4000 MHz

### The Big Deal

- Low noise figure, 0.5 dB
- High gain, 24.1 dB
- High IP3, +32.3 dBm
- High P1dB, 19.6 dBm



CASE STYLE: MMM1362

### Product Overview

Mini-Circuits' SAV-331+ is a MMIC D-PHEMT transistor with an operating frequency range from 10 to 4000 MHz. This model combines high gain with extremely low noise figure, resulting in lower overall system noise. Low NF and IP3 performance make it an ideal choice for sensitive receivers in communications systems. Manufactured using highly repeatable D-PHEMT\* technology, the unit comes housed in a tiny 4-lead SOT-343 package. This model requires external biasing and matching.

### Key Features

Feature	Advantages
Wideband, 10 to 4000 MHz	A single device covers many wireless communications bands including cellular, ISM, GSM, WCDMA, WiMax, WLAN, and more.
High IP3 vs. DC power consumption <ul style="list-style-type: none"><li>• +32.3 dBm at 300 MHz</li><li>• +38.7 dBm at 4000 MHz</li></ul>	The SAV-331+ matches industry leading IP3 performance relative to device size and power consumption. Enhanced linearity over a broad frequency range makes the device ideal for use in: <ul style="list-style-type: none"><li>• Driver amplifiers for complex waveform upconverter paths</li><li>• Drivers in linearized transmit systems</li></ul>
Combines high gain (24.1 dB) with very low noise Figure (0.5 dB)	The unique combination of high gain and low noise Figure results in lower overall system noise.

\* Depletion mode Pseudomorphic High Electron Mobility Transistor.

#### Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.  
B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.  
C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp)



# Ultra Low Noise, Medium Current D-PHEMT Transistor

## 10-4000 MHz

### Product Features

- Low Noise Figure, 0.5 dB typ. at 300 MHz
- Gain, 24.1 dB typ. at 300 MHz
- High Output IP3, +32.3 dBm typ. at 300 MHz
- Output Power at 1dB comp., +19.6 dBm typ. at 300 MHz
- Low Current, 60mA
- External biasing and matching required



## SAV-331+

CASE STYLE: MMM1362

**+RoHS Compliant**

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

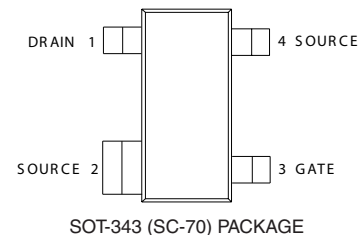
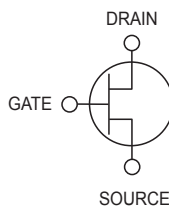
### Typical Applications

- Cellular
- ISM
- GSM
- WCDMA
- WiMax
- WLAN
- UNII and HIPERLAN

### General Description

Mini-Circuits' SAV-331+ is a MMIC D-PHEMT transistor with an operating frequency range from 10 to 4000 MHz. This model combines high gain with extremely low noise figure, resulting in lower overall system noise. Low NF and IP3 performance make it an ideal choice for sensitive receivers in communications systems. Manufactured using highly repeatable D-PHEMT\* technology, the unit comes housed in a tiny 4-lead SOT-343 package. This model requires external biasing and matching.

### simplified schematic and pin description



Function	Pin Number	Description
Source	2 & 4	Source terminal, normally connected to ground
Gate	3	Gate used for RF input
Drain	1	Drain used for RF output

\* Depletion mode Pseudomorphic High Electron Mobility Transistor.

#### Notes

- Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp)



Electrical Specifications at  $T_{AMB}=25^{\circ}\text{C}$ , Frequency 10 to 4000 MHz

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
<b>DC Specifications</b>						
$V_{GS}$	Operational Gate Voltage	$V_{DS}=4\text{V}$ , $I_{DS}=60\text{ mA}$	-0.81	-0.69	-0.57	V
$V_P$	Pinch-off Voltage	$V_{DS}=1.5\text{ V}$ , $I_{DS}=10\%$ of $I_{DSS}$		-0.81		V
$I_{DSS}$	Saturated Drain Current	$V_{DS}=4\text{V}$ , $V_{GS}=0\text{ V}$		228		mA
$G_M$	Transconductance	$V_{DS}=4\text{V}$ , $G_m=\Delta I_{DSS}/\Delta V_P$		282		mS
$I_{GDO}$	Gate to Drain Leakage Current	$V_{GD}=-5\text{V}$			1000	$\mu\text{A}$
$I_{GSS}$	Gate leakage Current	$V_{GD}=V_{GS}=-4\text{V}$			600	$\mu\text{A}$
<b>Specifications, <math>Z_0=50\text{ Ohms}</math> (Figure 1)*</b>						
NF	Noise Figure	$V_{DS}=4\text{V}$ , $I_{DS}=60\text{ mA}$				
			f=40 MHz	0.9		
			f=300 MHz	0.5		
			f=900 MHz	0.4		
			f=2000 MHz	0.5	0.8	
			f=4000 MHz	0.9		
Gain	Gain	$V_{DS}=4\text{V}$ , $I_{DS}=60\text{ mA}$				
			f=10 MHz	24.6		
			f=300 MHz	24.1		
			f=900 MHz	21.3		
			f=2000 MHz	16.6	18.3	
			f=4000 MHz	11.5		
OIP3	Output IP3	$V_{DS}=4\text{V}$ , $I_{DS}=60\text{ mA}$				
			f=10 MHz	30.9		
			f=300 MHz	32.3		
			f=900 MHz	33.5		
			f=2000 MHz	35.5		
			f=4000 MHz	38.7		
P1dB	Power output at 1 dB Compression	$V_{DS}=4\text{V}$ , $I_{DS}=60\text{ mA}$				
			f=10 MHz	19.1		
			f=300 MHz	19.6		
			f=900 MHz	20.2		
			f=2000 MHz	21.1		
			f=4000 MHz	21.8		
$\Theta_{JC}$	Thermal Resistance			109		$^{\circ}\text{C/W}$

\* Tested on Mini-Circuits TB-471+ test board.

Absolute Maximum Ratings<sup>(1)</sup>

Symbol	Parameter	Max.	Units
$V_{DS}$	Drain-Source Voltage <sup>2</sup>	5	V
$V_{GS}$	Gate-Source Voltage <sup>2</sup>	-5	V
$V_{GD}$	Gate-Drain Voltage <sup>2</sup>	-5	V
$I_{DS}$	Drain Current <sup>2</sup>	149	mA
$P_{DISS}$	Total Dissipated Power	400	mW
$P_{IN}$	RF Input Power	20	dBm
$T_{CH}$	Channel Temperature	150	$^{\circ}\text{C}$
$T_{OP}$	Operating Temperature	-40 to 85	$^{\circ}\text{C}$
$T_{STD}$	Storage Temperature	-65 to 150	$^{\circ}\text{C}$

Notes:

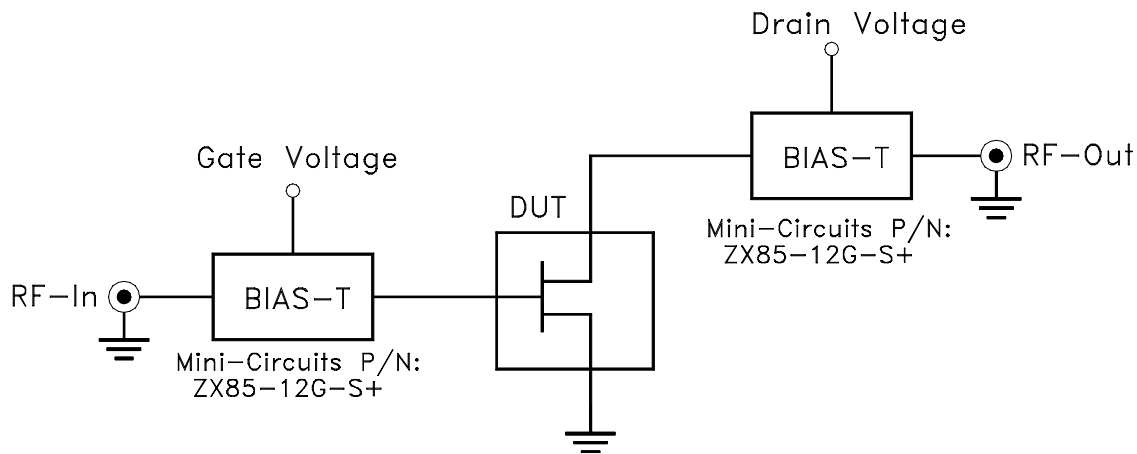
- (1) Operation of this device above any one of these parameters may cause permanent damage.  
 (2) Assumes DC quiescent conditions,  $V_{GS} = -0.51\text{ V}$ ,  $V_{DS} = 4\text{ V}$ .

## Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.  
 B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.  
 C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp)



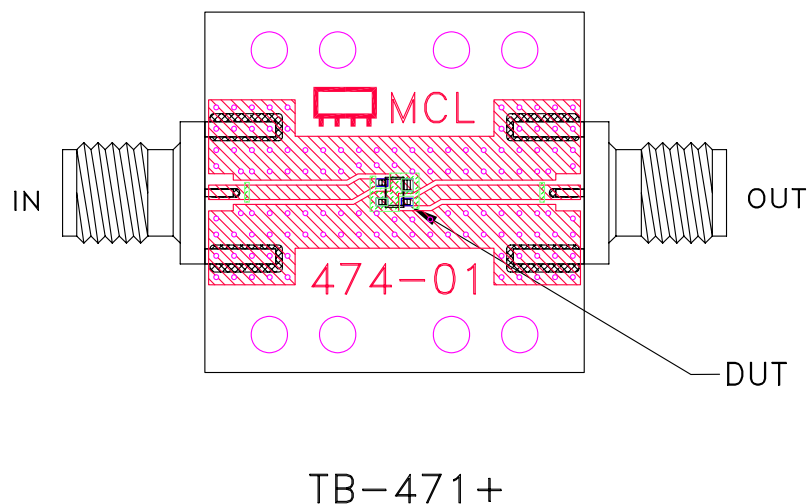
## Characterization Test Circuit



**Fig 1.** Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Test Board TB-471+) Gain, Output power at 1dB compression (P1 dB) and output IP3 (OIP3) are measured using R&S Network Analyzer ZVA-24. Noise Figure measured using keysight PNA-X.

**Conditions:**

1. Drain voltage (with reference to source,  $V_{DS}$ )= 4V as shown.
2. Gate Voltage (with reference to source,  $V_{GS}$ ) is set to obtain desired Drain-Source current ( $I_{DS}$ ) as shown in graphs or specification table.
3. Gain:  $P_{in} = -25\text{dBm}$
4. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
5. No external matching components used.

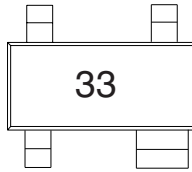


**Fig 2.** Test Board used for characterization, Mini-Circuits P/N TB-471+ (Material: Rogers 4350, Thickness: 0.02")

**Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp)

## Product Marking



### Additional Detailed Technical Information

Additional information is available on our web site [www.minicircuits.com](http://www.minicircuits.com). To access this information enter the model number on our web site home page.

#### Performance data, graphs, s-parameter data set (.zip file)

#### Case Style: MMM1362

Plastic molded SOT-343 (SC-70) style package, lead finish: matte tin

#### Suggested Layout for PCB Design: PL-300

#### Tape & Reel: F90

Standard quantities available on reel: 7" reels with 20, 50, 100, 200, 500, 1K, 2K, or 3K devices.

#### Characterization Test Board: TB-471+

#### Environmental Ratings: ENV08T2

### ESD Rating

Human Body Model (HBM): Class 0 (<250 V) in accordance with ANSI/ESD STM 5.1 - 2001

### MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020D

#### Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp)

